

Features

- High current capacity in compact package $I_c = 1.5A$.
- Epitaxial planar type
- Pb-Free package is available

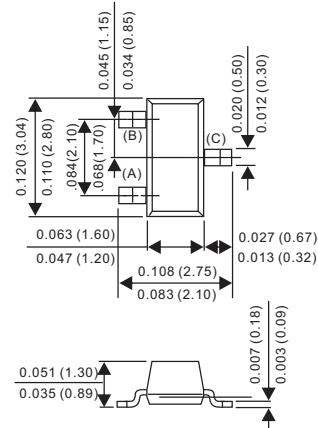
SOT23

ROHS
COMPLIANT

Pb-Free

Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, SOT-23
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Mounting Position : Any
- Weight : Approximated 0.008 gram



Dimensions in inches and (millimeters)

Maximum ratings (AT $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	Symbol	MAX.	UNIT
Collector-base voltage	V_{CBO}	40	V
Collector-emitter voltage	V_{CEO}	25	V
Emitter-base voltage	V_{EBO}	5.0	V
Collector current-continuoun	I_c	1500	mA

Thermal Characteristics

PARAMETER	Symbol	MIN.	TYP.	MAX.	UNIT
Total device dissipation FR-5 board (1) $T_A = 25^\circ\text{C}$	P_D			225	mW
Derate above 25°C				1.8	$\text{mW}/^\circ\text{C}$
Thermal resistance Junction to ambient	R_{BJA}			556	$^\circ\text{C}/\text{W}$
Total device dissipation alumina substrate(2) $T_A = 25^\circ\text{C}$	P_D			300	mW
Derate above 25°C				2.4	$\text{mW}/^\circ\text{C}$
Thermal resistance Junction to ambient	R_{BJA}			417	$^\circ\text{C}/\text{W}$
Operating Junction temperature Range	T_J	-55		+150	$^\circ\text{C}$
Storage temperature Range	T_{STG}	-55		+150	$^\circ\text{C}$

1.FR-5 = 1.0 X 0.75 X 0.062 in.

2.Alumina = 0.4 X 0.3 X 0.024 in. 99.5% alumina.

Electrical Characteristics (AT $T_A=25^\circ\text{C}$ unless otherwise noted)

Off characteristics

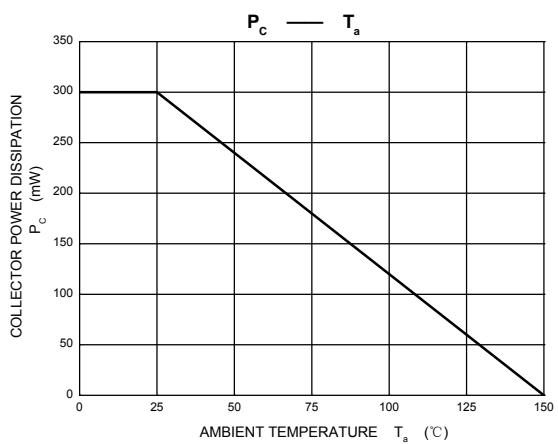
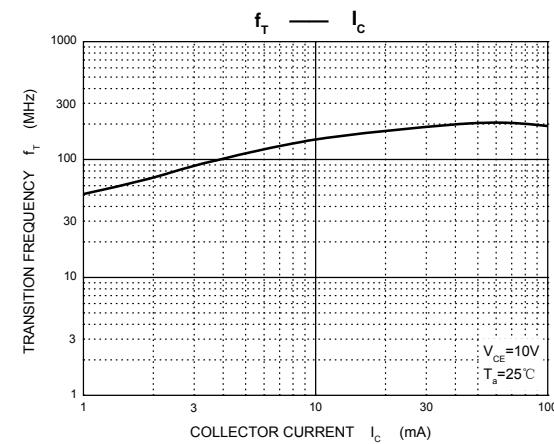
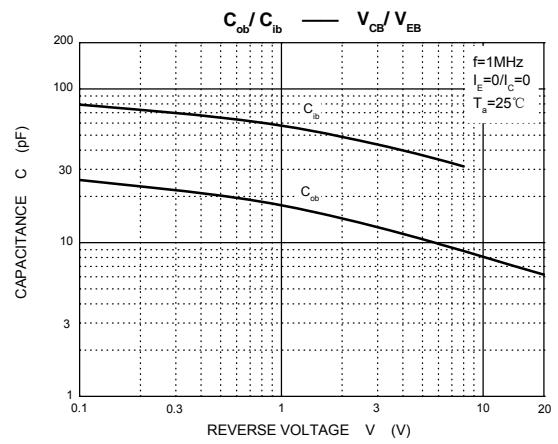
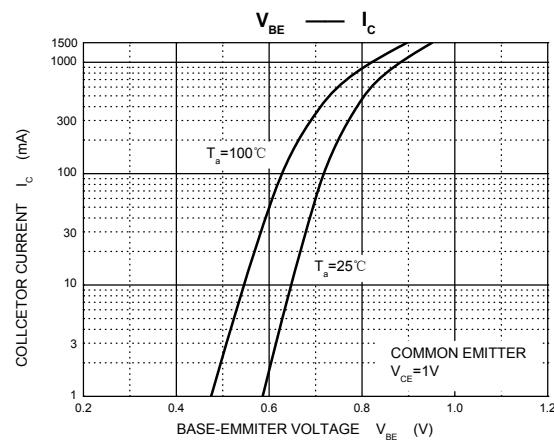
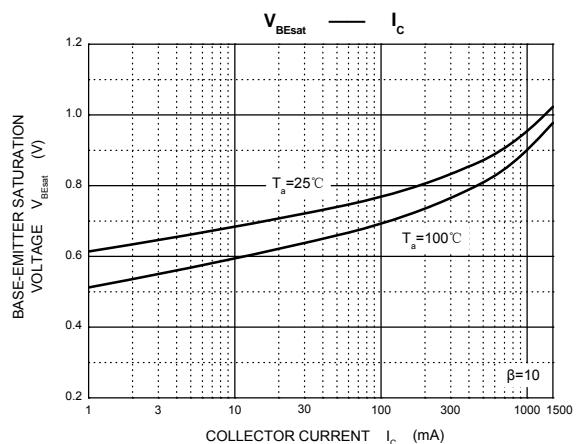
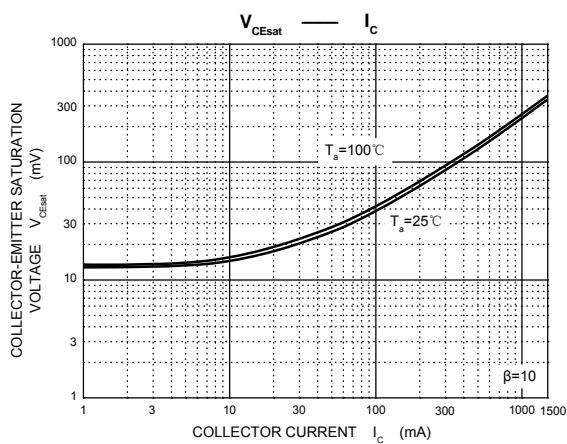
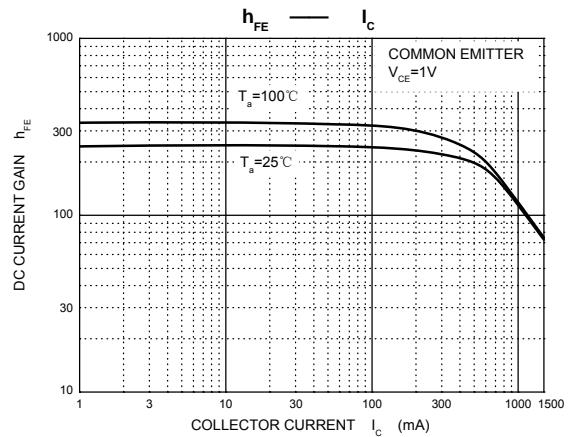
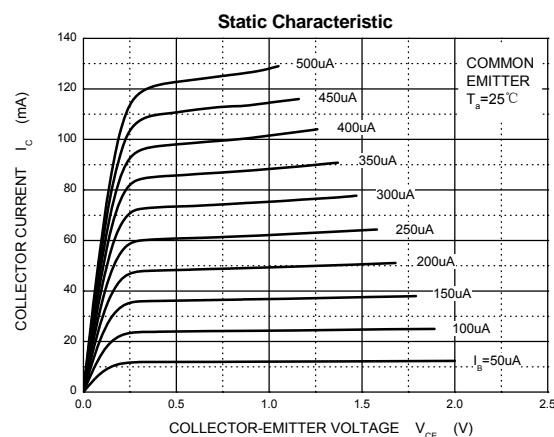
PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Collector-base breakdown voltage	$I_c = 100\mu\text{A}$	$V_{(\text{BR})\text{CBO}}$	40			V
Collector-emitter breakdown voltage	$I_c = 1.0\text{mA}$	$V_{(\text{BR})\text{CEO}}$	25			V
Emitter-base breakdown voltage	$I_E = 100\mu\text{A}$	$V_{(\text{BR})\text{EBO}}$	5.0			V
Collector cutoff current	$V_{CB} = 35\text{V}$	I_{CBO}			150	nA
Emitter cutoff current	$V_{EB} = 4.0\text{V}$	I_{EBO}			150	nA

On characteristics

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
DC current gain	$I_c = 100\text{mA}, V_{CE} = 1.0\text{V}$	$h_{\text{FE}}^{\text{Note}}$	80		400	
Collector-emitter saturation voltage	$I_c = 800\text{mA}, I_B = 80\text{mA}$	$V_{\text{CE}(\text{sat})}$			0.5	V

Note	*	L	H	J
	h_{FE}	80~200	200~350	300~400

Rating and characteristic curves



Pinning information

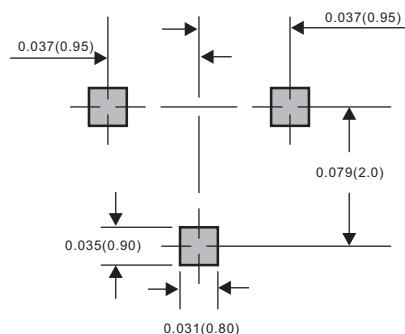
Pin	Simplified outline	Symbol
PinB Base		
PinC Collector		
PinE Emitter		

Marking

Type number	Marking code
SS8050	Y1

Suggested solder pad layout

SOT-23



Dimensions in inches and (millimeters)

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